查询28C5393供应商 Power Transistors

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2SC5393

Silicon NPN triple diffusion planar type

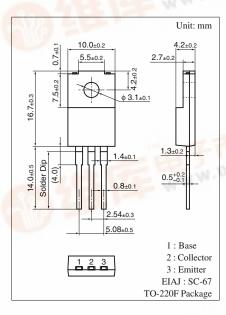
For high breakdown voltage high-speed switching WW.DZSC.COM

Features

- High-speed switching
- High collector to base voltage V_{CBO}
- Wide area of safe operation (ASO)
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

| Absolute Waximum Hatings $T_c = 23 C$ | | | | | | | |
|---------------------------------------|---------------------|------------------|-------------|-------|--|--|--|
| Parameter | | Symbol | Rating | Unit | | | |
| Collector to base voltage | | V _{CBO} | 600 | V | | | |
| Collector to emitter voltage | | V _{CES} | 600 | V | | | |
| | | V _{CEO} | 400 | V | | | |
| Emitter to base voltage | | V _{EBO} | 7 | V | | | |
| Peak collector current | | I _{CP} | 10 | А | | | |
| Collector current | | I _C | 5 | А | | | |
| Base current | | IB | 1 | А | | | |
| Collector power | $T_C = 25^{\circ}C$ | P _C | 40 | W | | | |
| dissipation | $T_a = 25^{\circ}C$ | 1.1 | 2 | 10 23 | | | |
| Junction temperature | | Tj | 150 | °C | | | |
| Storage temperature | | T _{stg} | -55 to +150 | °C | | | |
| | | | | | | | |

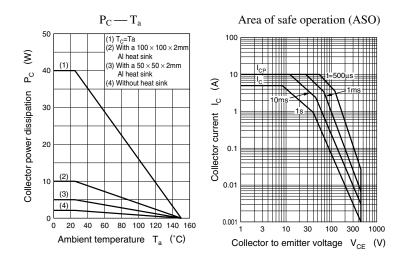
Absolute Maximum Ratings $T_c = 25^{\circ}C$



Electrical Characteristics $T_C = 25^{\circ}C$

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|----------------------|---|-----|-----|-----|------|
| Collector cutoff current | I _{CBO} | $V_{CB} = 600 \text{ V}, I_E = 0$ | - | 1 | 100 | μA |
| Emitter cutoff current | I_{EBO} | $V_{EB} = 5 V, I_C = 0$ | 115 | | 100 | μA |
| Forward current transfer ratio | h _{FE1} | $V_{CE} = 5 V, I_C = 0.1 A$ | 10 | | 60 | |
| | h _{FE2} | $V_{CE} = 5 V, I_C = 1.5 A$ | 8 | | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 1.5 \text{ A}, I_{\rm B} = 0.3 \text{ A}$ | | | 1 | V |
| Base to emitter saturation voltage | V _{BE(sat)} | $I_{\rm C} = 1.5 \text{ A}, I_{\rm B} = 0.3 \text{ A}$ | | | 2 | V |
| Transition frequency | f_T | $V_{CE} = 10 \text{ V}, I_C = 0.1 \text{ A}, f = 0.5 \text{ MHz}$ | | 30 | | MHz |
| Storage time | t _{stg} | $I_C = 2 A, I_{B1} = 0.4 A, I_{B2} = -0.8 A,$ | | | 2.0 | μs |
| Fall time | t _f | $V_{CC} = 150 \text{ V}$ | | | 0.3 | μs |





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